



2SA2099 / 2SC5888

High-Current Switching Applications

Applications

- Relay drivers, lamp drivers, motor drivers.

Features

- Adoption of MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.

Specifications

() : 2SA2099

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-50)60	V
Collector-to-Emitter Voltage	V_{CEO}		(-)50	V
Emitter-to-Base Voltage	V_{EB0}		(-)6	V
Collector Current	I_C		(-)10	A
Collector Current (Pulse)	I_{CP}		(-)13	A
Base Current	I_B		(-)2	A
Collector Dissipation	P_C		2	W
		$T_c=25^\circ\text{C}$	25	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics

 at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40\text{V}, I_E=0$			(-)10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$			(-)10	μA

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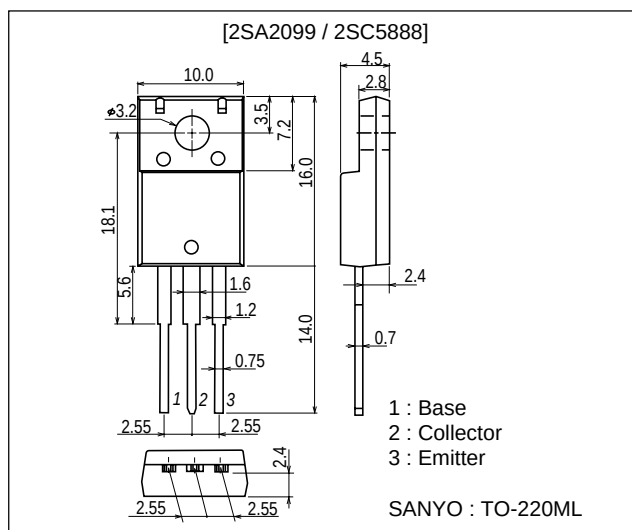
SANYO Electric Co.,Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

Package Dimensions

unit : mm

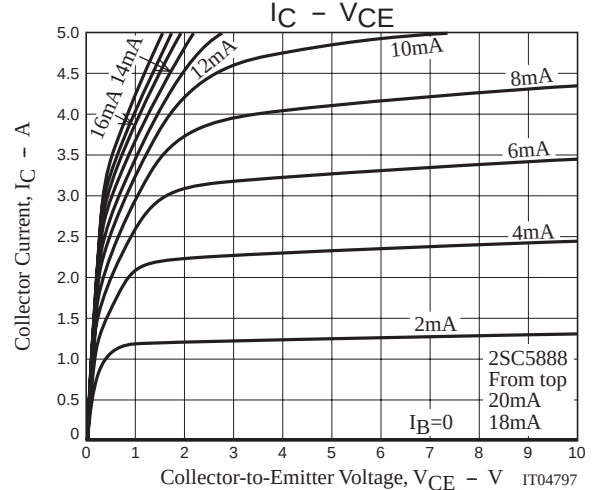
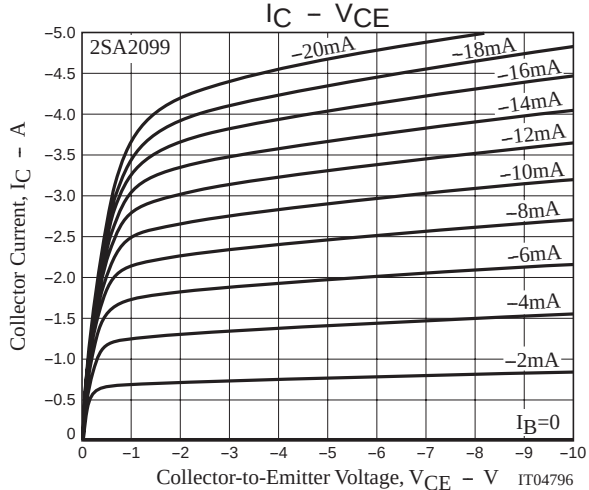
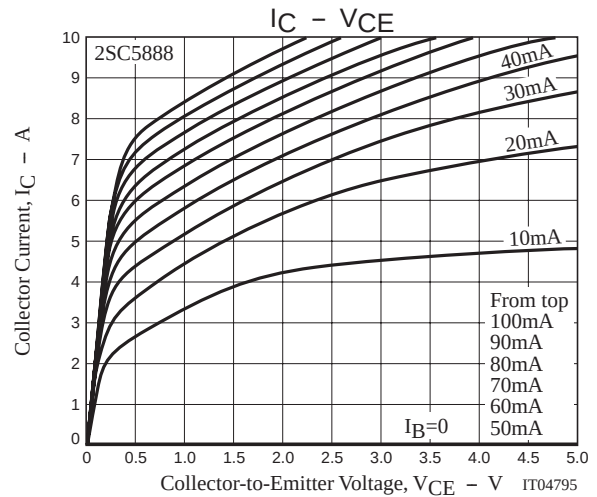
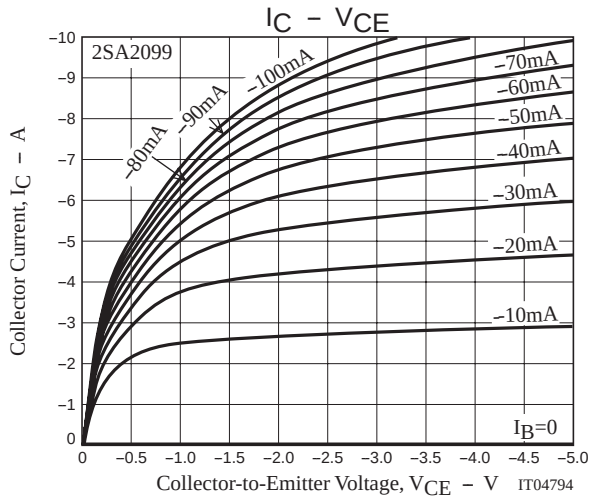
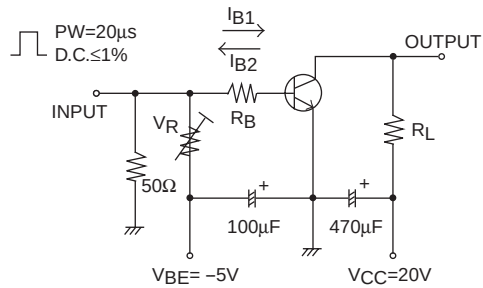
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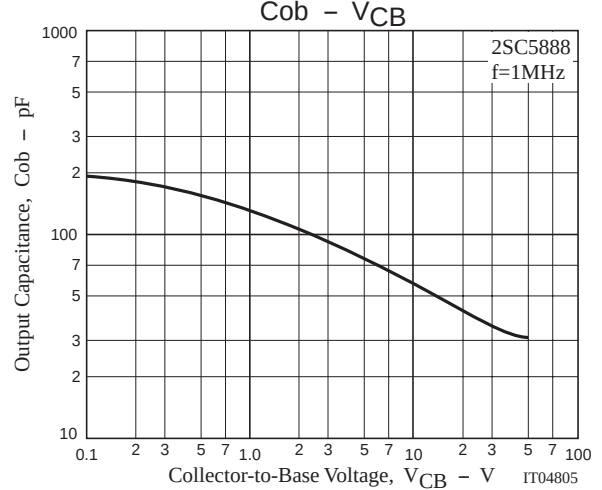
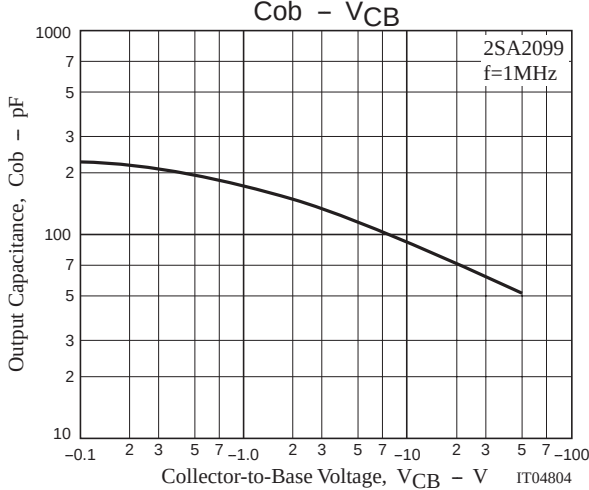
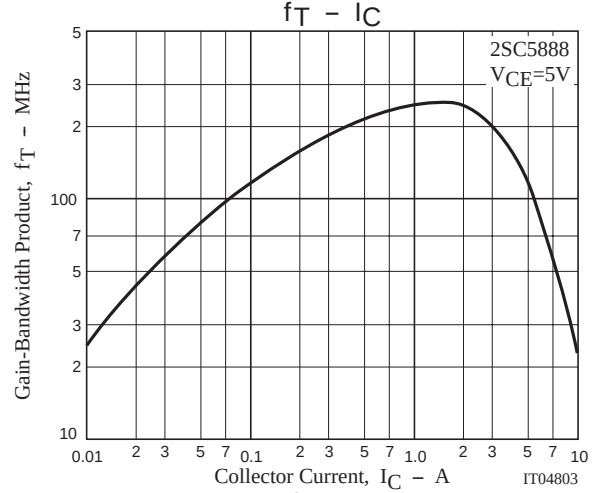
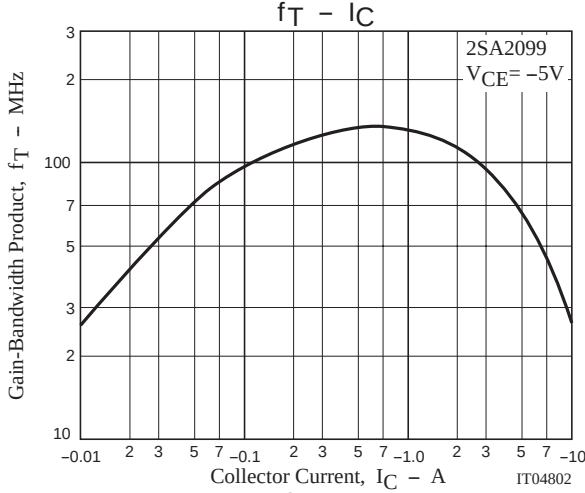
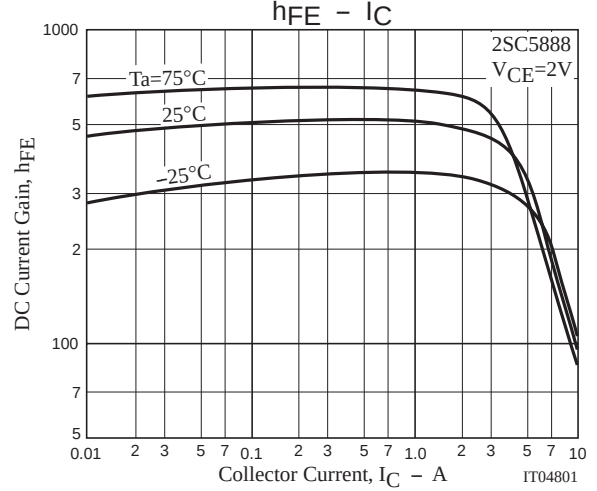
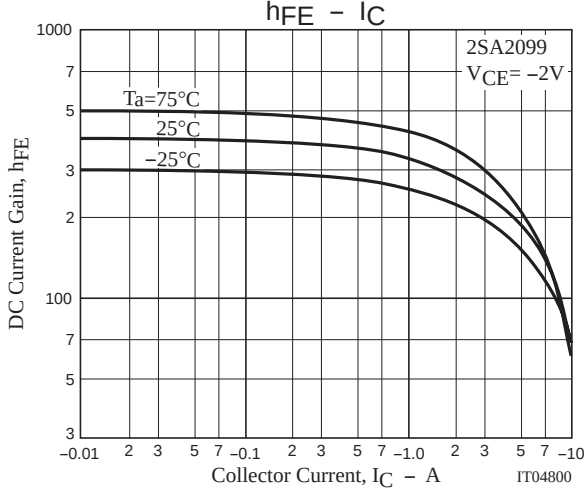
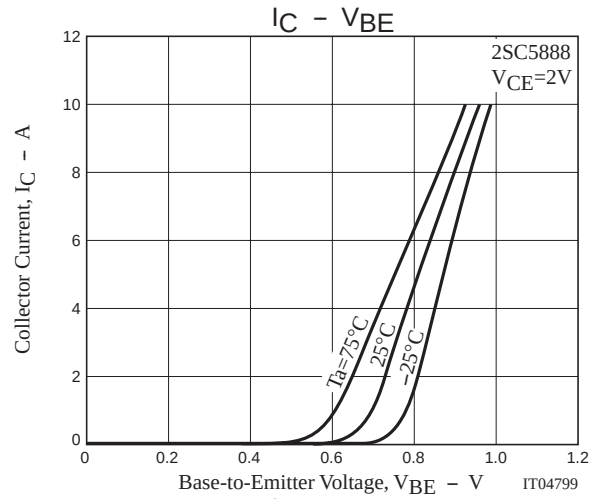
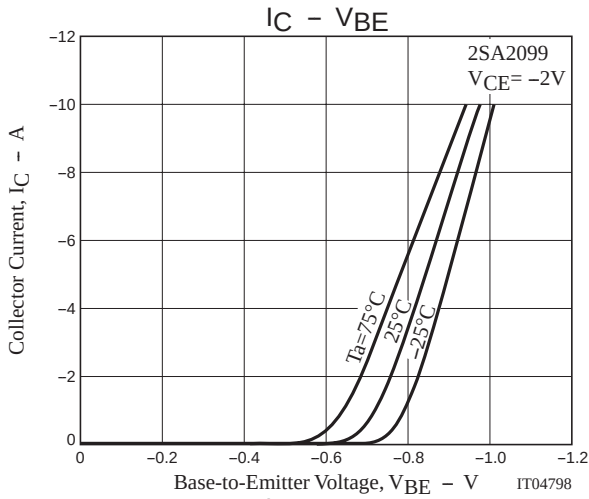


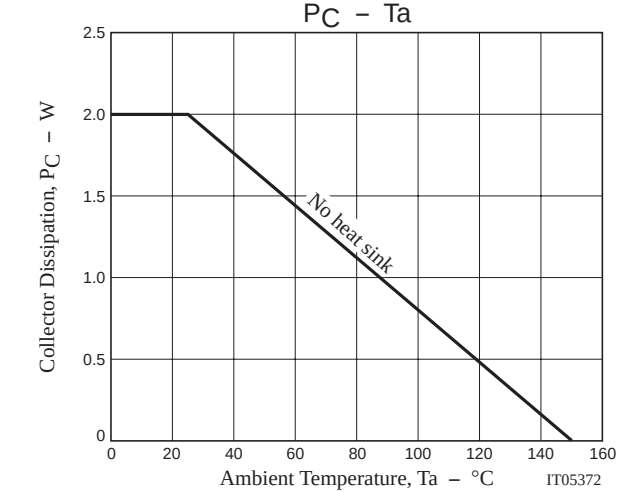
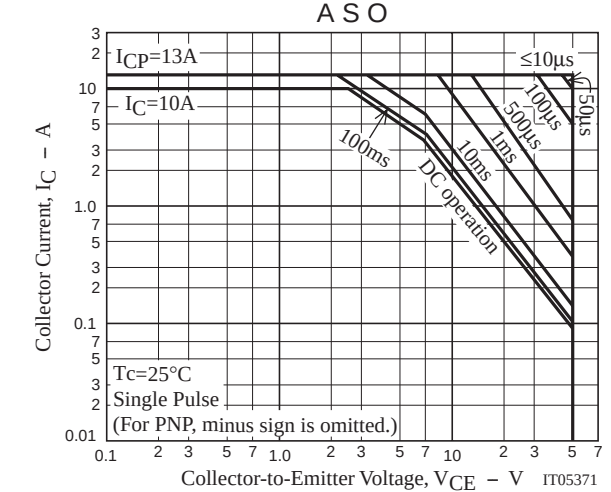
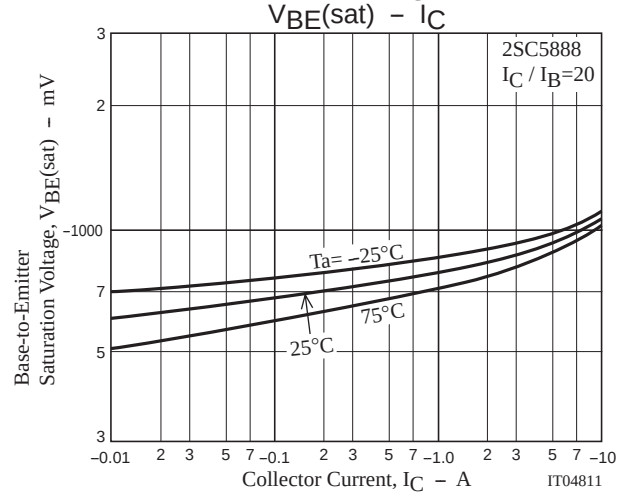
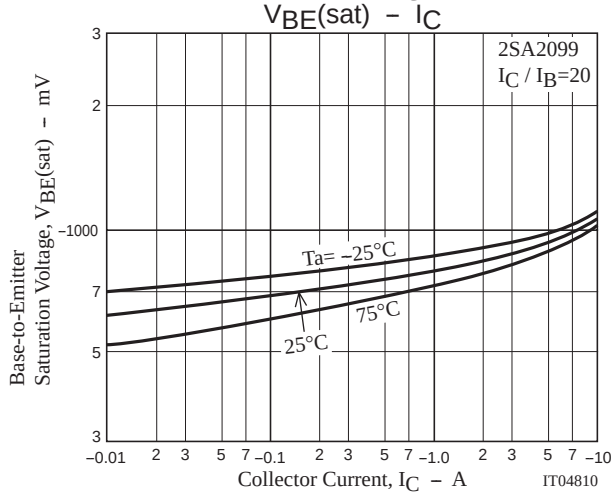
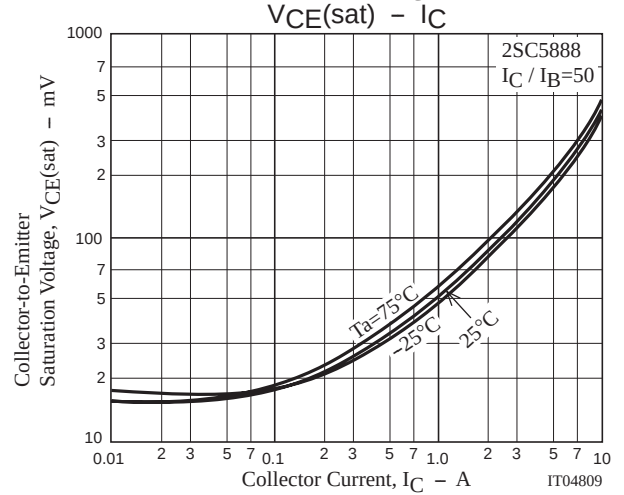
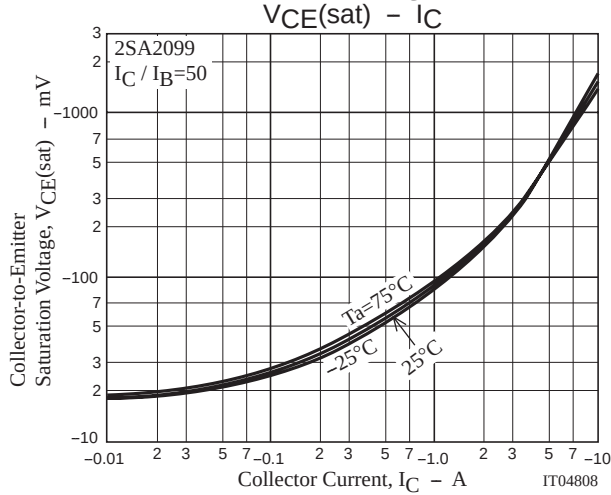
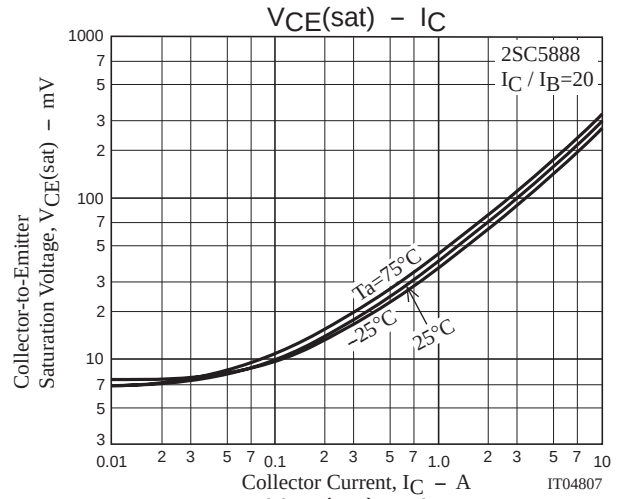
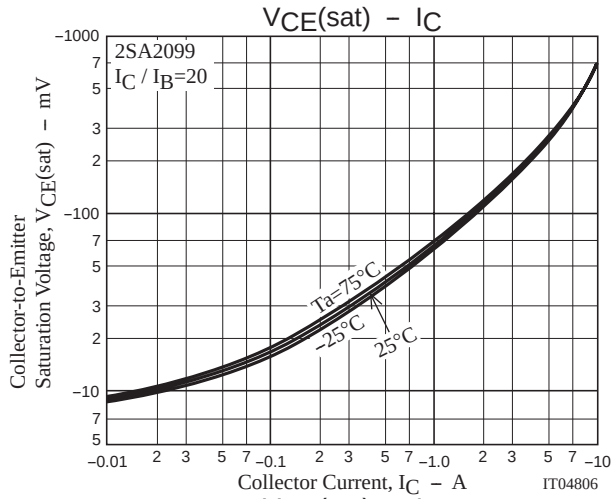
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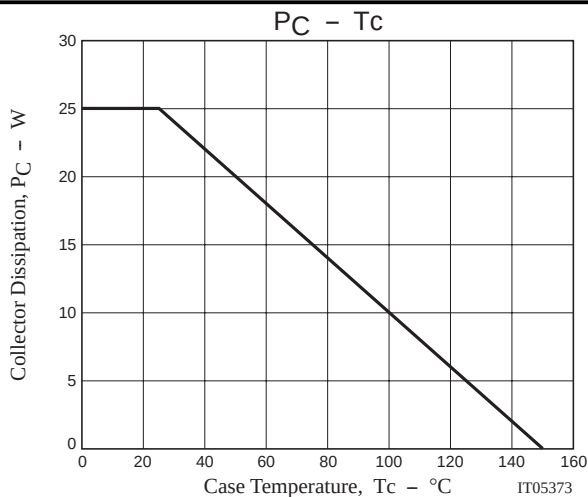
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
DC Current Gain	h_{FE}	$V_{CE}=(-)2V, I_C=(-)1A$	200		(560)700	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)5V, I_C=(-)1A$		(130)200		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10V, f=1MHz$		90(60)		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)5A, I_B=(-)250mA$		(-250)180	(-500)360	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)5A, I_B=(-)250mA$		(-)0.93	(-)1.4	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)100\mu A, I_E=0$	(-50)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)100\mu A, I_C=0$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		(70)40		ns
Storage Time	t_{stg}	See specified Test Circuit.		(650)1000		ns
Fall Time	t_f	See specified Test Circuit.		(60)80		ns

Switching Time Test Circuit









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